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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR NO301P

P-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

DESCRIPTION

The N0301P is a switching device, which can be driven directly by a 2.5 V power source.

This N0301P features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

FEATURES

- 2.5 V drive available
- · Low on-state resistance

RDS(on)1 = 75 m Ω MAX. (VGS = -4.5 V, ID = -2.0 A)

 $R_{DS(on)2} = 106 \text{ m}\Omega \text{ MAX}. \text{ (VGS = -2.5 V, ID = -2.0 A)}$

· Built-in gate protection diode

ORDERING INFORMATION

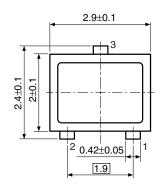
PART NUMBER	LEAD PLATING	PACKING	PACKAGE
N0301P-T1-AT	Pure Sn (Tin)	Tape 3000 p/reel	SOT-23F

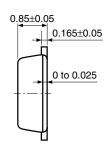
Marking: XV

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vss = 0 V)	VDSS	-30	V
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	∓12	V
Drain Current (DC)	I _{D(DC)}	∓4.0	Α
Drain Current (pulse) Note1	$I_{D(pulse)}$	∓18	Α
Total Power Dissipation	P _{T1}	0.2	W
Total Power Dissipation Note2	P _{T2}	1.3	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C

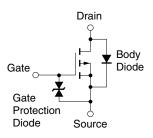
PACKAGE DRAWING (Unit: mm)





- 1: Source
- 2: Gate
- 3: Drain

EQUIVALENT CIRCUIT



- **Notes 1.** PW \leq 10 μ s, Duty Cycle \leq 1%
 - **2.** Mounted on FR-4 board of 50 mm \times 50 mm \times 1.6 mm, copper foil 100%, t \leq 5 sec.

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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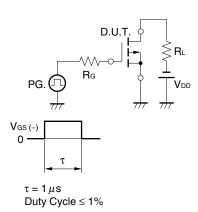


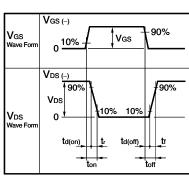
ELECTRICAL CHARACTERISTICS (TA = 25°C)

	_ `	·	1	_	_	
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = -30 V, V _{GS} = 0 V			-10	μΑ
Gate Leakage Current	Igss	$V_{GS} = \mp 12 \text{ V}, V_{DS} = 0 \text{ V}$			∓10	μΑ
Gate to Source Cut-off Voltage	V _{GS(off)}	$V_{DS} = -10 \text{ V}, I_{D} = -1.0 \text{ mA}$	-0.5		-1.5	V
Forward Transfer Admittance ^{Note}	yfs	$V_{DS} = -10 \text{ V}, I_{D} = -2.0 \text{ A}$	2.5			S
Drain to Source On-state ResistanceNote	R _{DS(on)1}	$V_{GS} = -4.5 \text{ V}, I_D = -2.0 \text{ A}$		40	75	mΩ
	R _{DS(on)2}	$V_{GS} = -2.5 \text{ V}, I_{D} = -2.0 \text{ A}$		71	106	mΩ
Input Capacitance	Ciss	V _{DS} = -10 V,		780		pF
Output Capacitance	Coss	V _G S = 0 V,		140		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		120		pF
Turn-on Delay Time	t _{d(on)}	$V_{DD} = -15 \text{ V}, I_D = -2.0 \text{ A},$		12		ns
Rise Time	tr	V _{GS} = -4.5 V,		10		ns
Turn-off Delay Time	t _{d(off)}	$R_G = 10 \Omega$		58		ns
Fall Time	t f			44		ns
Total Gate Charge	Q _G	V _{DD} = -24 V,		9.5		nC
Gate to Source Charge	Qgs	V _{GS} = -4.5 V,		1.9		nC
Gate to Drain Charge	Q _{GD}	I _D = -4.0 A		4.5		nC
Body Diode Forward Voltage ^{Note}	VF(S-D)	I _F = 4.0 A, V _{GS} = 0 V		0.87		V
Reverse Recovery Time	Trr	I _F = 4.0 A, V _{GS} = 0 V,		41		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/μs		16		nC

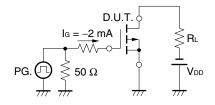
Note Pulsed

TEST CIRCUIT 1 SWITCHING TIME



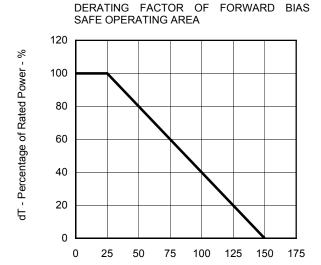


TEST CIRCUIT 2 GATE CHARGE

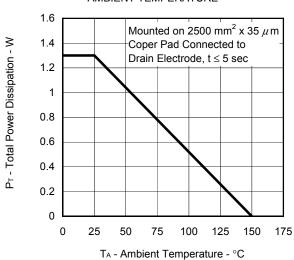




TYPICAL CHARACTERISTICS (TA = 25°C)

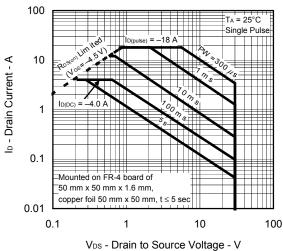


TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE

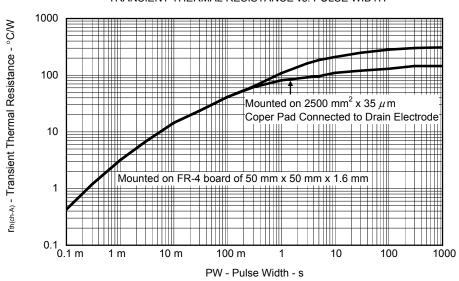


FORWARD BIAS SAFE OPERATING AREA

T_A - Ambient Temperature - °C



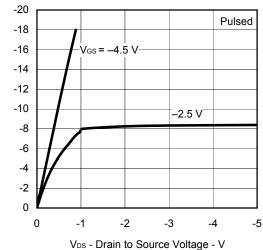
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



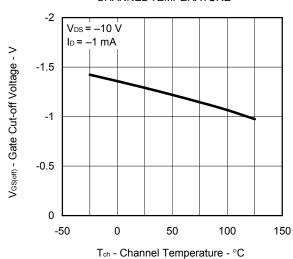
3

lo - Drain Current - A

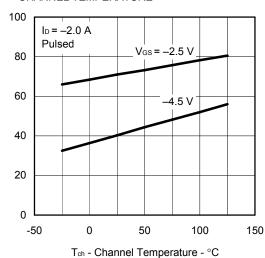
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



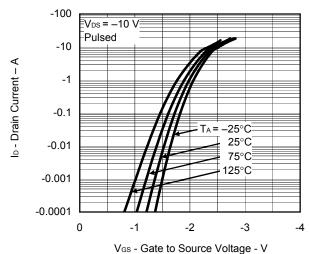
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



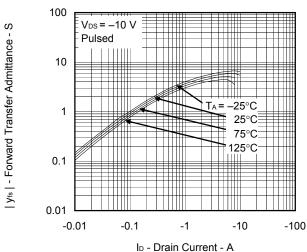
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



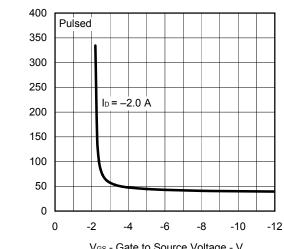
FORWARD TRANSFER CHARACTERISTICS



FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

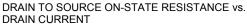


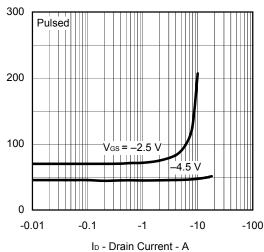
Vgs - Gate to Source Voltage - V

RDS(m) - Drain to Source On-state Resistance - m\Omega

R_{DS(m)} - Drain to Source On-state Resistance - mΩ

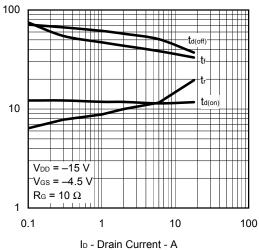
 $\mathsf{R}_{\mathsf{DS}(m)}$ - Drain to Source On-state Resistance - $m\Omega$





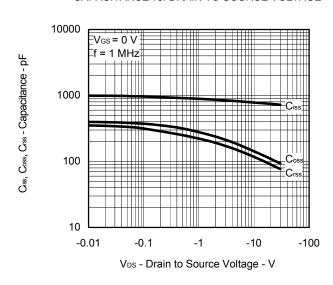
td(on), tr, td(off), tr - Switching Time - ns

IF - Diode Forward Current - A

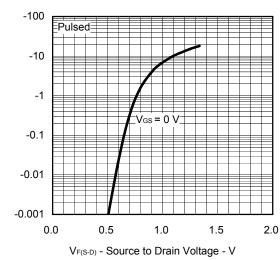


SWITCHING CHARACTERISTICS

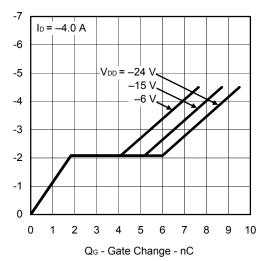
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



DYNAMIC INPUT/OUTPUT CHARACTERISTICS



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